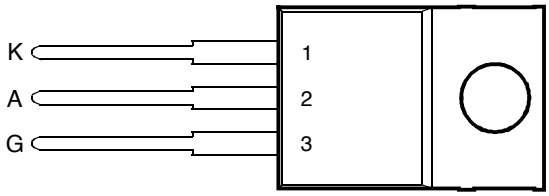
THE DATASHEET OF

TIC108M

- **5 A Continuous On-State Current**
- **20 A Surge-Current**
- **Glass Passivated Wafer**
- **400 V to 800 V Off-State Voltage**
- **Max I_{GT} of 1 mA**

This series is obsolete and not recommended for new designs.

TO-220 PACKAGE
(TOP VIEW)



Pin 2 is in electrical contact with the mounting base.

MDC1ACA

absolute maximum ratings over operating case temperature (unless otherwise noted)

RATING		SYMBOL	VALUE	UNIT
Repetitive peak off-state voltage (see Note 1)	TIC108D TIC108M TIC108S TIC108N	V_{DRM}	400 600 700 800	V
Repetitive peak reverse voltage	TIC108D TIC108M TIC108S TIC108N	V_{RRM}	400 600 700 800	V
Continuous on-state current at (or below) 80°C case temperature (see Note 2)		$I_{T(RMS)}$	5	A
Average on-state current (180° conduction angle) at (or below) 80°C case temperature (see Note 3)		$I_{T(AV)}$	3.2	A
Surge on-state current (see Note 4)		I_{TSM}	20	A
Peak positive gate current (pulse width ≤ 300 µs)		I_{GM}	0.2	A
Peak gate power dissipation (pulse width ≤ 300 µs)		P_{GM}	1.3	W
Average gate power dissipation (see Note 5)		$P_{G(AV)}$	0.3	W
Operating case temperature range		T_C	-40 to +110	°C
Storage temperature range		T_{stg}	-40 to +125	°C
Lead temperature 1.6 mm from case for 10 seconds		T_L	230	°C

NOTES: 1. These values apply when the gate-cathode resistance R_{GK} = 1 kΩ.
2. These values apply for continuous dc operation with resistive load. Above 80°C derate linearly to zero at 110°C.
3. This value may be applied continuously under single phase 50 Hz half-sine-wave operation with resistive load. Above 80°C derate linearly to zero at 110°C.
4. This value applies for one 50 Hz half-sine-wave when the device is operating at (or below) the rated value of peak reverse voltage and on-state current. Surge may be repeated after the device has returned to original thermal equilibrium.
5. This value applies for a maximum averaging time of 20 ms.

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electrical characteristics at 25°C case temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
I_{DRM}	Repetitive peak off-state current	V_D = rated V_{DRM}	R_{GK} = 1 kΩ	T_C = 110°C			400	µA
I_{RRM}	Repetitive peak reverse current	V_R = rated V_{RRM}	I_G = 0	T_C = 110°C			1	mA
I_{GT}	Gate trigger current	V_{AA} = 12 V	R_L = 100 Ω	$t_{p(g)} \geq 20$ µs	0.2	0.5	1	mA
V_{GT}	Gate trigger voltage	V_{AA} = 12 V $t_{p(g)} \geq 20$ µs	R_L = 100 Ω R_{GK} = 1 kΩ	T_C = - 40°C			1.2	V
		V_{AA} = 12 V $t_{p(g)} \geq 20$ µs	R_L = 100 Ω R_{GK} = 1 kΩ		0.4	0.6	1	
		V_{AA} = 12 V $t_{p(g)} \geq 20$ µs	R_L = 100 Ω R_{GK} = 1 kΩ	T_C = 110°C	0.2			
I_H	Holding current	V_{AA} = 12 V Initiating I_T = 20 mA	R_{GK} = 1 kΩ	T_C = - 40°C		3.5	15	mA
		V_{AA} = 12 V Initiating I_T = 20 mA	R_{GK} = 1 kΩ			2	10	
V_T	On-state voltage	I_T = 5 A	(see Note 6)			1.3	1.7	V
dv/dt	Critical rate of rise of off-state voltage	V_D = rated V_D	R_{GK} = 1 kΩ	T_C = 110°C		20		V/µs

NOTE 6: This parameter must be measured using pulse techniques, t_p = 300 µs, duty cycle ≤ 2 %. Voltage sensing-contacts, separate from the current carrying contacts, are located within 3.2 mm from the device body.

thermal characteristics

PARAMETER		MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction to case thermal resistance			3.5	°C/W
$R_{\theta JA}$	Junction to free air thermal resistance			62.5	°C/W

THERMAL INFORMATION

AVERAGE ANODE ON-STATE CURRENT DERATING CURVE

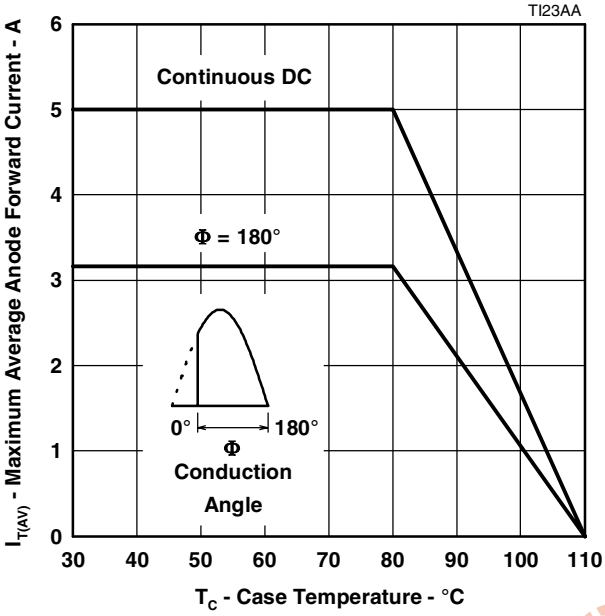

Figure 1.

MAX ANODE POWER DISSIPATED vs ANODE ON-STATE CURRENT

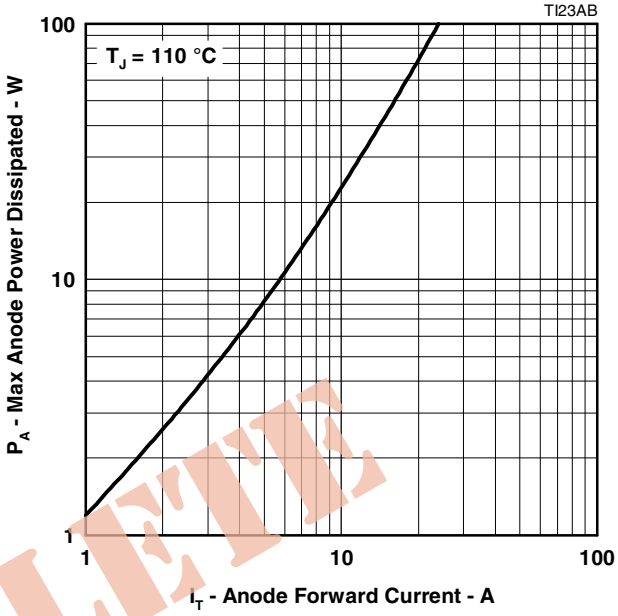

Figure 2.

SURGE ON-STATE CURRENT vs CYCLES OF CURRENT DURATION

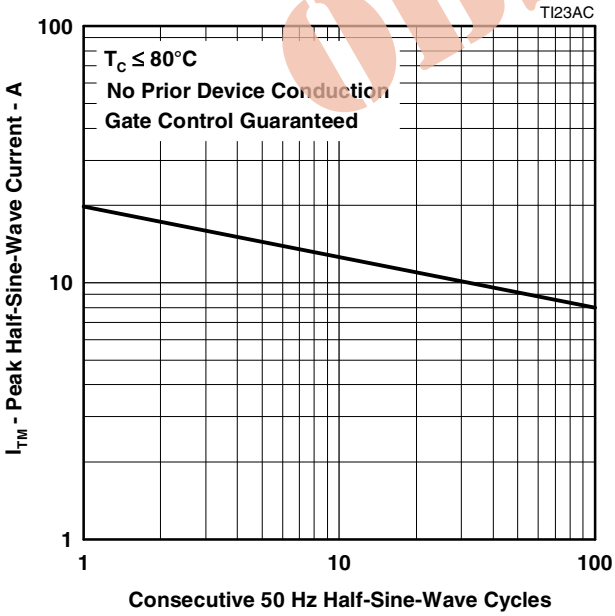

Figure 3.

TRANSIENT THERMAL RESISTANCE vs CYCLES OF CURRENT DURATION

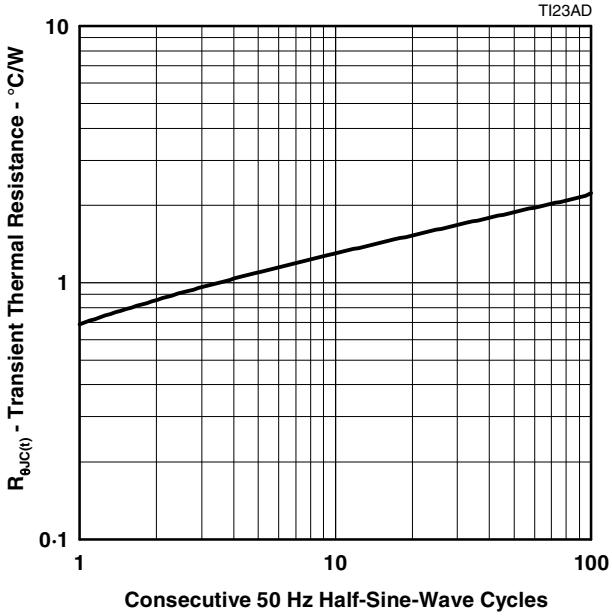

Figure 4.

TYPICAL CHARACTERISTICS

GATE TRIGGER CURRENT vs CASE TEMPERATURE

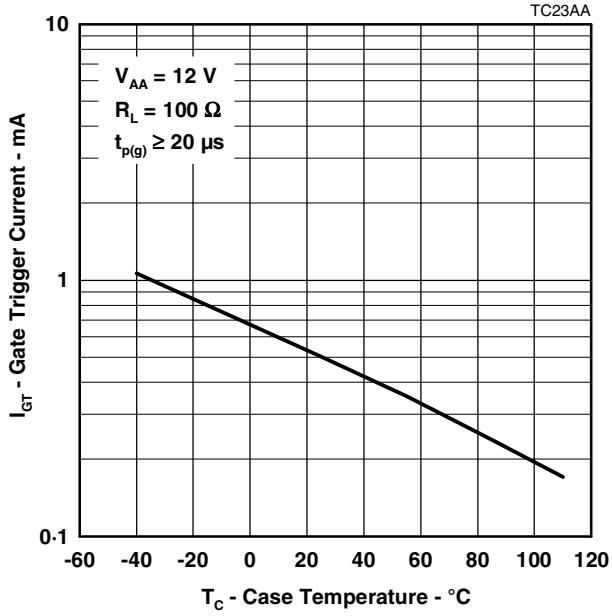

Figure 5.

GATE TRIGGER VOLTAGE vs CASE TEMPERATURE

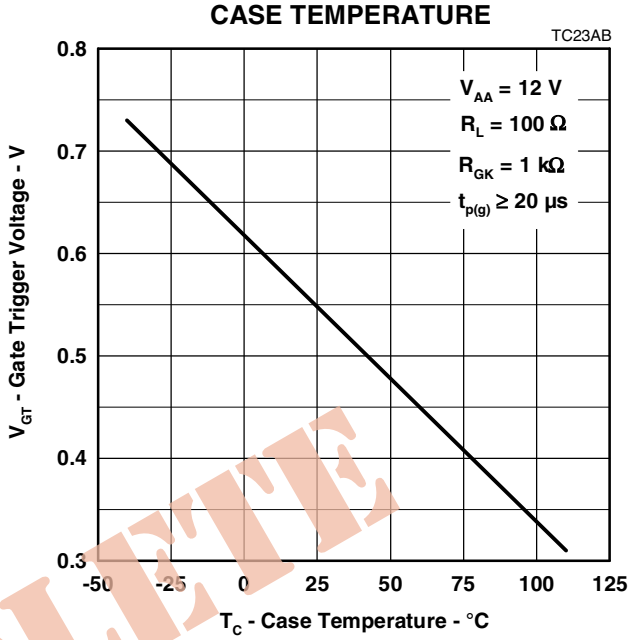

Figure 6.

HOLDING CURRENT vs CASE TEMPERATURE

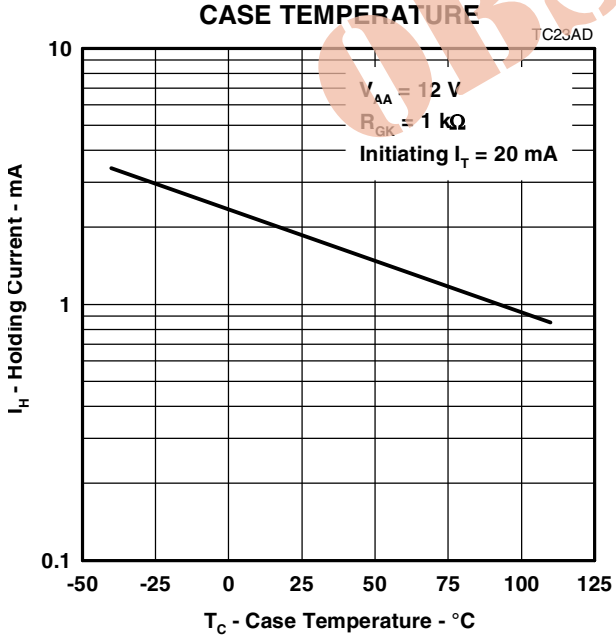

Figure 7.

PEAK ON-STATE VOLTAGE vs PEAK ON-STATE CURRENT

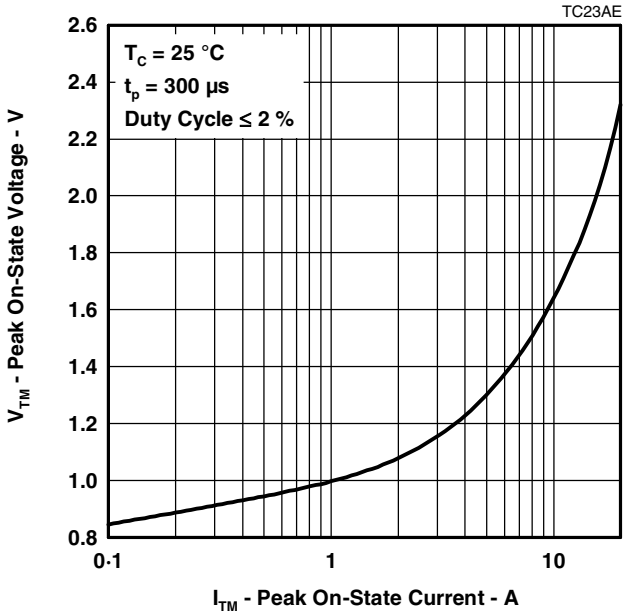

Figure 8.

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- Alternative Solution
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